

MIC5335

Dual-Channel, High-Performance 300 mA µCap ULDO

Features

- 2.3V to 5.5V Input Voltage Range
- Ultra-Low Dropout Voltage: 75 mV @ 300 mA
- Ultra-Small 1.6 mm x 1.6 mm x 0.55 mm 6-Lead Thin DFN Package
- Independent Enable Pins
- High PSRR (over 65 dB @ 1 kHz)
- 300 mA Output Current per LDO
- µCap Stable with 1 µF Ceramic Capacitor
- Low Quiescent Current: 90 µA/LDO
- Fast Turn-On Time: 30 µs
- Thermal Shutdown Protection
- Current Limit Protection

Applications

- Mobile Phones
- PDAs
- GPS Receivers
- Portable Electronics
- Portable Media Players
- Digital Still and Video Cameras

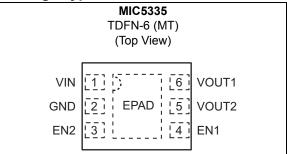
General Description

The MIC5335 is a high current density, dual Ultra-Low Dropout (ULDO) linear regulator. The MIC5335 is ideally suited for portable electronics that demand overall high performance in a very small form factor. The MIC5335 is offered in the ultra-small 1.6 mm x 1.6 mm x 0.55 mm 6-lead Thin DFN package, which is only 2.56 mm² in area. The MIC5335 has an exceptional thermal performance for applications that demand higher power dissipation in a very small footprint. In addition, the MIC5335 integrates two high-performance 300 mA LDOs with independent enable functions and offers high PSRR, eliminating the need for a bypass capacitor.

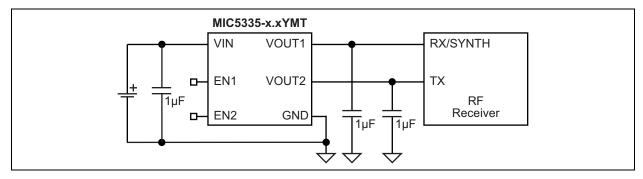
The MIC5335 is a μ Cap design that enables operation with very small output capacitors for stability, thereby reducing required board space and component cost.

The MIC5335 is available in fixed-output voltages. Additional voltages are available upon customer request.

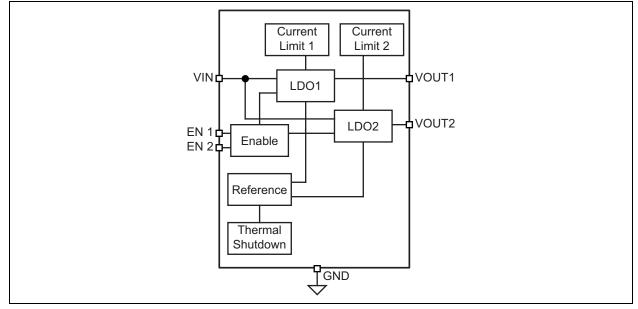
Package Type



Typical Application Circuit



Functional Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Supply Voltage (V _{IN})	0V to +6V
Enable Input Voltage (V _{EN})	
Power Dissipation	Internally Limited, Note 1
Lead Temperature (Soldering, 3 sec.)	+260°C
Storage Temperature (T _S)	–65°C to +150°C
ESD Rating (Note 2)	

Operating Ratings ††

Supply Voltage (V _{IN})	+2.3V to +5.5V
Enable Input Voltage (V _{EN})	0V to V _{IN}
Junction Temperature (T ₁)	
Thermal Resistance, TDFN-6 (θ _{JA})	

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

†† Notice: The device is not guaranteed to function outside its operating ratings.

- **Note 1:** The maximum allowable power dissipation of any T_A (ambient temperature) is $P_{D(MAX)} = (T_{J(MAX)} T_A)/\theta_{JA}$. Exceeding the maximum allowable power dissipation will result in excessive die temperature and the regulator will go into thermal shutdown.
 - **2:** Devices are ESD sensitive. Handling precautions are recommended. Human body model, $1.5 \text{ k}\Omega$ in series with 100 pF.

ELECTRICAL CHARACTERISTICS

Electrical Characteristics: $V_{IN} = EN1 = EN2 = V_{OUT} + 1.0V$; higher of the two regulator outputs, $I_{OUTLDO1} = I_{OUTLDO2} = 100 \ \mu$ A; $C_{OUT1} = C_{OUT2} = 1 \ \mu$ F; $T_J = +25^{\circ}$ C, **bold** values indicate -40° C $\leq T_J \leq +125^{\circ}$ C, unless noted. Note 1

Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions
		-2.0	_	2.0	%	Variation from nominal V _{OUT}
Output Voltage Accuracy		-3.0	_	3.0	%	Variation from nominal V _{OUT} ; –40°C to +125°C
Line Desulation		_	0.02	0.3	%/V	$V_{IN} = V_{OUT} + 1V$ to 5.5V; $I_{OUT} = 100 \ \mu A$
Line Regulation	_			0.6	%0/V	—
Load Regulation	_	—	0.3	2.0	%	I _{OUT} = 100 μA to 300 mA
	V _{DO}		0.1	_		I _{OUT} = 100 μA
Dropout Voltage, Note 2			25	75		I _{OUT} = 100 mA
			35	100	mV	I _{OUT} = 150 mA
		_	75	200		I _{OUT} = 300 mA

Note 1: Specification for packaged product only.

2: Dropout voltage is defined as the input-to-output differential at which the output voltage drops 2% below its nominal V_{OUT}. For outputs below 2.3V, the dropout voltage is the input-to-output differential with the minimum input voltage 2.3V.

ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: $V_{IN} = EN1 = EN2 = V_{OUT} + 1.0V$; higher of the two regulator outputs, $I_{OUTLDO1} = I_{OUTLDO2} = 100 \ \mu$ A; $C_{OUT1} = C_{OUT2} = 1 \ \mu$ F; $T_J = +25^{\circ}$ C, **bold** values indicate -40° C $\leq T_J \leq +125^{\circ}$ C, unless noted. Note 1

Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions
	I _{GND}		90	125		EN1 = High; EN2 = Low; I _{OUT} = 100 μA to 300 mA
Ground Current			90	125	μA	EN1 = Low; EN2 = High; I _{OUT} = 100 μA to 300 mA
			150	220		EN1 = EN2 = High; I _{OUT1} = 300 mA, I _{OUT2} = 300 mA
Ground Current in Shutdown	I _{SHDN}		0.01	2	μA	EN1 = EN2 = 0V
Dinnlo Dejection	PSRR		65		٩D	f = 1 kHz; C _{OUT} = 1.0 μF
Ripple Rejection			45		dB	f = 20 kHz; C _{OUT} = 1.0 μF
Current Limit	I _{LIM}	340	550	950	mA	V _{OUT} = 0V
Output Voltage Noise			90		μV_{RMS}	C _{OUT} = 1.0 μF; 10 Hz to 100 kHz
Enable Inputs (EN1/EN2)						
	M			0.2	v	Logic low
Enable Input Voltage	V _{EN}	1.1			V	Logic high
Frankla lanut Ourmant		_	0.01	1		V _{IL} ≤ 0.2V
Enable Input Current	I _{EN}		0.01	1	μA	V _{IH} ≥ 1.0V
Turn-On Time (see Timing	g Diagram))				
Turn-On Time (LDO1 and LDO2)	t _{ON}	_	30	100	μs	C _{OUT} = 1.0 μF

Note 1: Specification for packaged product only.

2: Dropout voltage is defined as the input-to-output differential at which the output voltage drops 2% below its nominal V_{OUT}. For outputs below 2.3V, the dropout voltage is the input-to-output differential with the minimum input voltage 2.3V.

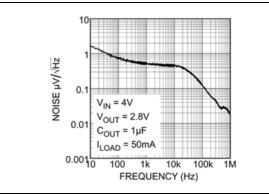
TEMPERATURE SPECIFICATIONS

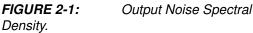
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions	
Temperature Ranges							
Storage Temperature Range	Τ _S	-65	—	+150	°C	—	
Lead Temperature	—	—	—	+260	°C	Soldering, 3 sec.	
Junction Temperature Range	TJ	-40	_	+125	°C	—	
Package Thermal Resistances							
Thermal Resistance, 1.6x1.6 TDFN 6-Ld	θ_{JA}	_	100	_	°C/W	_	

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +125°C rating. Sustained junction temperatures above +125°C can impact the device reliability.

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.





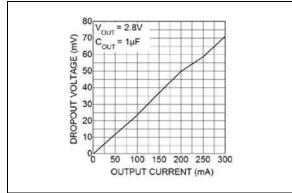
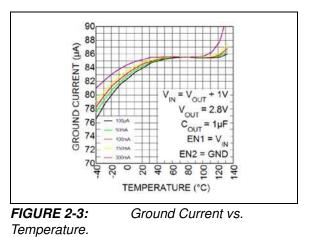
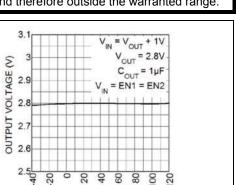


FIGURE 2-2: Dropout Voltage vs. Output Current.







Output Voltage vs.

TEMPERATURE (°C)

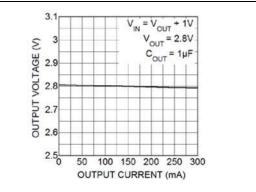
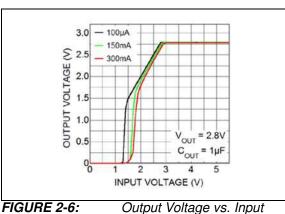


FIGURE 2-5: Current.

Output Voltage vs. Output



Voltage.

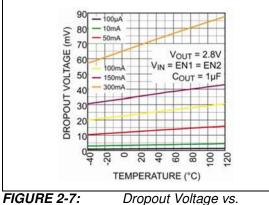


FIGURE 2-7: Dro Temperature.

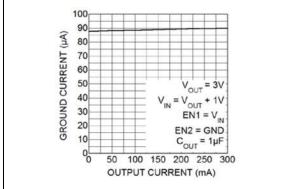


FIGURE 2-8: Current.

Ground Current vs. Output

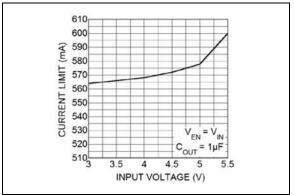


FIGURE 2-9:

Current Limit.

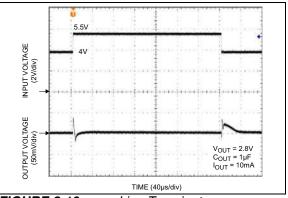


FIGURE 2-10: Line Transient.

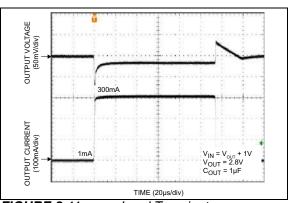
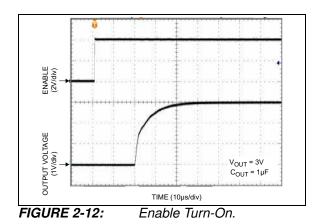


FIGURE 2-11: Load Transient.



3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

Pin Number	Pin Name	Description
1	VIN	Supply Input.
2	GND	Ground.
3	EN2	LDO2 Enable Active-High Input. Logic High = On; Logic Low = Off; Do not leave floating.
4	EN1	LDO1 Enable Active-High Input. Logic High = On; Logic Low = Off; Do not leave floating.
5	VOUT2	Regulator Output – LDO2.
6	VOUT1	Regulator Output – LDO1.
EPAD	ePad	Exposed heat sink pad connected internally to ground.

4.0 APPLICATION INFORMATION

4.1 Enable/Shutdown

The MIC5335 comes with dual active-high enable pins that allow each regulator to be enabled independently. Forcing the enable pin low disables the regulator and sends it into a "zero" off-mode current state. In this state, current consumed by the regulator goes nearly to zero. Forcing the enable pin high enables the output voltage. The active-high enable pin uses CMOS technology and the enable pin cannot be left floating; a floating enable pin may cause an indeterminate state on the output.

4.2 Input Capacitor

The MIC5335 is a high-performance, high-bandwidth device. Therefore, it requires a well-bypassed input supply for optimal performance. A 1 μ F capacitor is required from the input to ground to provide stability. Low-ESR ceramic capacitors provide optimal performance at a minimum of space. Additional high-frequency capacitors, such as small-valued NPO dielectric-type capacitors, help filter out high-frequency noise and are good practice in any RF-based circuit.

4.3 Output Capacitor

The MIC5335 requires an output capacitor of 1 μ F or greater to maintain stability. The design is optimized for use with low-ESR ceramic chip capacitors. High-ESR capacitors may cause high frequency oscillation. The output capacitor can be increased, but performance has been optimized for a 1 μ F ceramic output capacitor and does not improve significantly with larger capacitance.

X7R/X5R dielectric-type ceramic capacitors are recommended because of their temperature performance. X7R-type capacitors change capacitance by 15% over their operating temperature range and are the most stable type of ceramic capacitors on the market. Z5U and Y5V dielectric capacitors change value by as much as 50% and 60%, respectively, over their operating temperature ranges. To use a ceramic chip capacitor with Y5V dielectric, the value must be much higher than an X7R ceramic capacitor to ensure the same minimum capacitance over the equivalent operating temperature range.

4.4 No-Load Stability

Unlike many other voltage regulators, the MIC5335 will remain stable and in regulation with no load. This is especially important in CMOS RAM keep-alive applications.

4.5 Thermal Considerations

The MIC5335 is designed to provide 300 mA of continuous current for both outputs in a very small package. Maximum ambient operating temperature can be calculated based upon the output current and the voltage drop across the part. Given that the input voltage is 3.3V, the output voltage is 2.8V for V_{OUT1} , 2.5V for V_{OUT2} , and the output current is 300 mA. The actual power dissipation of the regulator circuit can be determined using the equation:

EQUATION 4-1:

$$\begin{split} P_{D} &= (V_{IN} - V_{OUT1}) \times I_{OUT1} + \\ (V_{IN} - V_{OUT2}) \times I_{OUT2} + V_{IN} \times I_{GND} \end{split}$$

$$P_{D} &= (3.3V - 2.8V) \times 300 mA + (3.3V - 2.5V) \times 300 mA \\ P_{D} &= 0.39 W \end{split}$$

Because this device is CMOS and the ground current is typically <100 μ A over the load range, the power dissipation contributed by the ground current is < 1% and can be ignored for Equation 4-1.

To determine the maximum ambient operating temperature of the package, use the junction-to-ambient thermal resistance of the device and the following basic equation:

EQUATION 4-2:

$$P_{D(MAX)} = \frac{T_{J(MAX)} - T_A}{\theta_{JA}}$$

Where:

 $T_{J(MAX)}$ = 125°C, the max. junction temp of the die. θ_{JA} = 100°C/W thermal resistance.

The table that follows shows junction-to-ambient thermal resistance for the MIC5335 in the Thin DFN package.

TABLE 4-1: THERMAL RESISTANCE

θ _{JA} Recommended Minimum Footprint	θ _{JC}
100°C/W	2°C/W

Substituting P_D for $P_{D(MAX)}$ and solving for the ambient operating temperature will give the maximum operating conditions for the regulator circuit. The junction-to-ambient thermal resistance for the minimum footprint is 100°C/W. The maximum power dissipation must not be exceeded for proper operation.

For example, when operating the MIC5335-MFYML at an input voltage of 3.3V and 300 mA loads on each output with a minimum footprint layout, the maximum ambient operating temperature T_A can be determined as follows:

EQUATION 4-3:

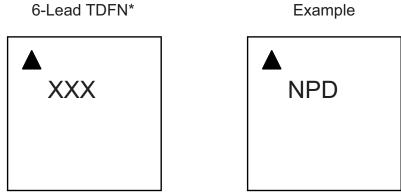
$$0.39W = \frac{125^{\circ}C - T_A}{100^{\circ}C/W}$$
$$T_A = 86^{\circ}C$$

Therefore, a 2.8V/2.5V application with 300 mA at each output current can accept an ambient operating temperature of 86° C in a 1.6 mm x 1.6 mm Thin DFN package.

PACKAGING INFORMATION 5.0

5.1 Package Marking Information

6-Lead TDFN*

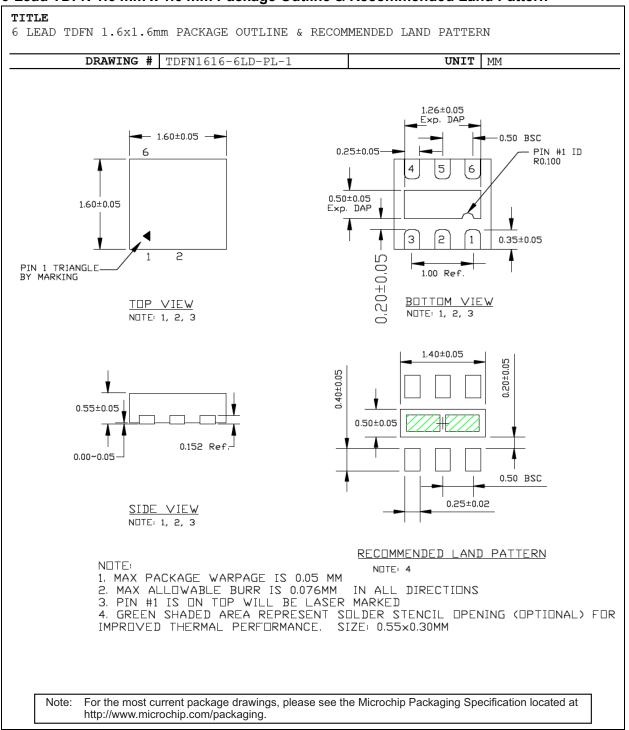


For a detailed breakdown of part numbers, their markings, and voltages, please see Table 5-1.

Legend:	XXX Y YY WW NNN @3 * •, ▲, ▼ mark).	Product code or customer-specific information Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code Pb-free JEDEC [®] designator for Matte Tin (Sn) This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package. Pin one index is identified by a dot, delta up, or delta down (triangle
t t	be carriec characters the corpora	t the full Microchip part number cannot be marked on one line, it will l over to the next line, thus limiting the number of available for customer-specific information. Package may or may not include ate logo. () and/or Overbar (⁻) symbol may not be to scale.

Part Number	Marking	Voltage	Part Number	Marking	Voltage
MIC5335-GFYMT	GPF	1.8V/1.5V	MIC5335-PGYMT	PPG	3.0V/1.8V
MIC5335-GWYMT	GPW	1.8V/1.6V	MIC5335-PJYMT	PPJ	3.0V/2.5V
MIC5335-GGYMT	GPG	1.8V/1.8V	MIC5335-PKYMT	PPK	3.0V/2.6V
MIC5335-JGYMT	JPG	2.5V/1.8V	MIC5335-PMYMT	PPM	3.0V/2.8V
MIC5335-JJYMT	JPJ	2.5V/2.5V	MIC5335-PNYMT	PPN	3.0V/2.85V
MIC5335-KDYMT	KPD	2.6V/1.85	MIC5335-PPYMT	PPP	3.0V/3.0V
MIC5335-KGYMT	KPG	2.6V/1.8V	MIC5335-SFYMT	SPF	3.3V/1.5V
MIC5335-LLYMT	LPL	2.7V/2.7V	MIC5335-SGYMT	SPG	3.3V/1.8V
MIC5335-MFYMT	MPF	2.8V/1.5V	MIC5335-SJYMT	SPJ	3.3V/2.5V
MIC5335-MGYMT	MPG	2.8V/1.8V	MIC5335-SKYMT	SPK	3.3V/2.6V
MIC5335-MKYMT	MPK	2.8V/2.6V	MIC5335-SLYMT	SPL	3.3V/2.7V
MIC5335-MMYMT	MPM	2.8V/2.8V	MIC5335-SMYMT	SPM	3.3V/2.8V
MIC5335-NDYMT	NPD	2.85V/1.85V	MIC5335-SNYMT	SPN	3.3V/2.85V
MIC5335-NKYMT	NPK	2.85V/2.6V	MIC5335-SOYMT	SPO	3.3V/2.9V
MIC5335-NNYMT	NPN	2.85V/2.85V	MIC5335-SPYMT	SPP	3.3V/3.0V
MIC5335-OFYMT	OPF	2.9V/1.5V	MIC5335-SRYMT	SPR	3.3V/3.2V
MIC5335-OGYMT	OPG	2.9V/1.8V	MIC5335-SSYMT	SPS	3.3V/3.3V
MIC5335-OOYMT	OPO	2.9V/2.9V	MIC5335-XXYMT	XPX	3.15V/3.15V

TABLE 5-1: PACKAGE MARKING



6-Lead TDFN 1.6 mm x 1.6 mm Package Outline & Recommended Land Pattern

NOTES:

APPENDIX A: REVISION HISTORY

Revision A (June 2018)

- Converted Micrel document MIC5335 to Microchip data sheet template DS20006039A.
- Minor grammatical text changes throughout.
- Addition of MIC5335-XXYMT option in Table 5-1 and Product Identification System.
- Updated Package Type drawing.
- Updated Functional Block Diagram drawing.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

	N/V	×	N/V	~~~	Examples:			
Device Part No.	-XX Voltage Option MIC5335:	X Junction Temp. Range Dual-Chanr	XX Package	- <u>XX</u> Media Type nance 300 mA	a) MIC5335-GFYMT-TR:	MIC5335, 1.8V/1.5V Voltage Option, -40°C to +125°C Temperature Range, 6-Lead 1.6 mm x 1.6 mm TDFN, 5,000/Reel		
Device:	GF = 1.8V/ GG = 1.8V/ GW = 1.8V/	μCap ULDC 1.5V 1.8V /1.6V			b) MIC5335-JJYMT-TR:	MIC5335, 2.5V/2.5V Voltage Option, -40°C to +125°C Temperature Range, 6-Lead 1.6 mm x 1.6 mm TDFN, 5,000/Reel		
	JG = 2.5V/1 JJ = 2.5V/2 KD = 2.6V/ ² KG = 2.6V/ ² LL = 2.7V/2 MF = 2.8V/ ² MG = 2.8V/	.5V 1.85V 1.8V .7V 1.5V			c) MIC5335-MKYMT-TR:	MIC5335, 2.8V/2.6V Voltage Option,40°C to +125°C Temperature Range, 6-Lead 1.6 mm x 1.6 mm TDFN, 5,000/Reel		
	MG = 2.8V/ MK = 2.8V/ MM = 2.8V/ ND = 2.85V NK = 2.85V NN = 2.85V OF = 2.9V/	2.6V /2.8V //1.85V //2.6V //2.85V			d) MIC5335-OGYMT-TR:	MIC5335, 2.9V/1.8V Voltage Option, -40°C to +125°C Temperature Range, 6-Lead 1.6 mm x 1.6 mm TDFN, 5,000/Reel		
Voltage Option:	OG = 2.9V/1.8V OG = 2.9V/2.9V PG = 3.0V/1.8V PJ = 3.0V/2.5V PK = 3.0V/2.6V PM = 3.0V/2.8V			e) MIC5335-PJYMT-TR:	MIC5335, 3.0V/2.5V Voltage Option, -40°C to +125°C Temperature Range, 6-Lead 1.6 mm x 1.6 mm TDFN, 5,000/Reel			
	PN = 3.0V/2 PP = 3.0V/2 SF = 3.3V/1 SG = 3.3V/2 SJ = 3.3V/2 SK = 3.3V/2	.0V/2.85V .0V/3.0V .3V/1.5V .3V/1.8V .3V/2.5V			f) MIC5335-SGYMT-TR:	MIC5335, 3.3V/1.8V Voltage Option,40°C to +125°C Temperature Range, 6-Lead 1.6 mm x 1.6 mm TDFN, 5,000/Reel		
	SL = 3.3V/2 SM = 3.3V/2 SN = 3.3V/2 SO = 3.3V/2 SP = 3.3V/2 SR = 3.3V/2 SS = 3.3V/2	2.8V 2.85V 2.9V 3.0V 3.2V			g) MIC5335-SRYMT-TR:	MIC5335, 3.3V/3.2V Voltage Option, -40°C to +125°C Temperature Range, 6-Lead 1.6 mm x 1.6 mm TDFN, 5,000/Reel		
Junction Temperature Range:	XX = 3.15V		RoHS-Complia	nt	h) MIC5335-XXYMT-TR:	MIC5335, 3.15V/3.15V Voltage Option, -40°C to +125°C Temperature Range, 6-Lead 1.6 mm x 1.6 mm TDFN, 5,000/Reel		
Package:		6-Lead 1.6 mm x	1.6 mm TDFN		Note 1: Tape and Reel identifier only appears in th catalog part number description. This iden used for ordering purposes and is not prin			
Media Type:	TR = !	5,000/Reel			the device package. Check with your Sales Office for package availability Tape and Reel option.			

NOTES:

Note the following details of the code protection feature on Microchip devices:

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